

1. Global joint venture starts operations as WeEn Semiconductors

Dear customer,

As from November 9th, 2015 NXP Semiconductors N.V. and Beijing JianGuang Asset Management Co. Ltd established Bipolar Power joint venture (JV), **WeEn Semiconductors**, which will be used in future Bipolar Power documents together with new contact details.

In this document where the previous NXP references remain, please use the new links as shown below.

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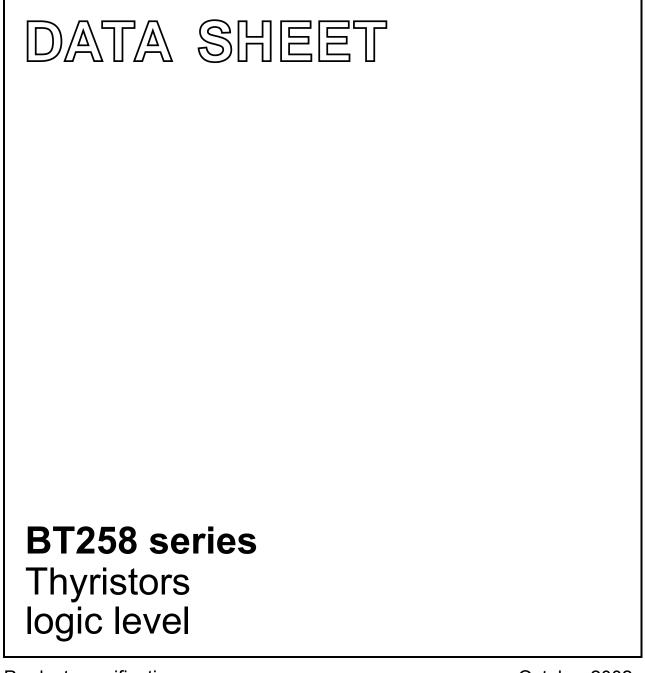
If you have any questions related to this document, please contact our nearest sales office via email or phone (details via <u>salesaddresses@ween-semi.com</u>).

Thank you for your cooperation and understanding,

WeEn Semiconductors



DISCRETE SEMICONDUCTORS



Product specification

October 2002



BT258 series

Thyristors logic level

GENERAL DESCRIPTION

Passivated, sensitive gate thyristors in a plastic envelope, intended for use in general purpose switching and phase control applications. These devices are intended to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

PINNING - TO220AB

PIN

1

2

3

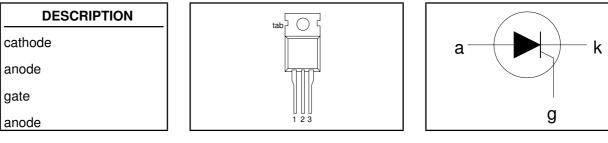
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QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	MAX.	MAX.	UNIT
$V_{\text{DRM}}, \\ V_{\text{RRM}} \\ I_{\text{T(AV)}} \\ I_{\text{T(RMS)}} \\ I_{\text{TSM}}$	BT258- Repetitive peak off-state voltages Average on-state current RMS on-state current Non-repetitive peak on-state current	500R 500 5 8 75	600R 600 5 8 75	800R 800 5 8 75	V A A A

PIN CONFIGURATION

SYMBOL



LIMITING VALUES

gate

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.		UNIT	
$V_{\text{drm}}, V_{\text{rrm}}$	Repetitive peak off-state voltages		-	-500R 500 ¹	-600R 600 ¹	-800R 800	v
I _{T(AV)} I _{T(RMS)} I _{TSM}	Average on-state current RMS on-state current Non-repetitive peak on-state current	half sine wave; $T_{mb} \le 111$ °C all conduction angles half sine wave; $T_j = 25$ °C prior to surge	-	5 8		A A	
l²t dI⊤/dt	I ² t for fusing Repetitive rate of rise of on-state current after	$\begin{array}{l} t = 10 \text{ ms} \\ t = 8.3 \text{ ms} \\ t = 10 \text{ ms} \\ I_{TM} = 10 \text{ A}; I_G = 50 \text{ mA}; \\ dI_G/dt = 50 \text{ mA}/\mu s \end{array}$	- - -		75 82 28 50		A A A²s A/µs
$\begin{array}{l} I_{GM} \\ V_{RGM} \\ P_{GM} \\ P_{G(AV)} \\ T_{stg} \\ T_{j} \end{array}$	triggering Peak gate current Peak reverse gate voltage Peak gate power Average gate power Storage temperature Operating junction temperature	over any 20 ms period	- - - -40 -		2 5 0.5 150 125 ²		o°o°≾≪

¹ Although not recommended, off-state voltages up to 800V may be applied without damage, but the thyristor may switch to the on-state. The rate of rise of current should not exceed 15 A/µs.

² Note: Operation above 110°C may require the use of a gate to cathode resistor of $1k\Omega$ or less.

Product specification

Thyristors	BT258 series
logic level	

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-mb}	Thermal resistance		-	-	2.0	K/W
R _{th j-a}	junction to mounting base Thermal resistance junction to ambient	in free air	-	60	-	K/W

STATIC CHARACTERISTICS

 $T_j = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{GT}	Gate trigger current	$V_{\rm D} = 12 \text{ V}; \text{ I}_{\rm T} = 0.1 \text{ A}$	-	50	200	μA
	Latching current	$V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$	-	0.4	10	mΑ
	Holding current	$V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$	-	0.3	6	mA
V _T	On-state voltage	$I_{T} = 16 A$	-	1.3	1.6	V
V _{GT}	Gate trigger voltage	$\dot{V}_{\rm D} = 12 \text{ V}; \text{ I}_{\rm T} = 0.1 \text{ A}$	-	0.4	1.5	V
		$V_{D} = V_{DRM(max)}$; $I_{T} = 0.1 \text{ A}$; $T_{j} = 110 \text{ °C}$	0.1	0.2	-	V
I _D , I _R	Off-state leakage current	$V_D = V_{DRM(max)}^{ORM(max)}; V_R = V_{RRM(max)}; T_j = 125 \degree C$	-	0.1	0.5	mA

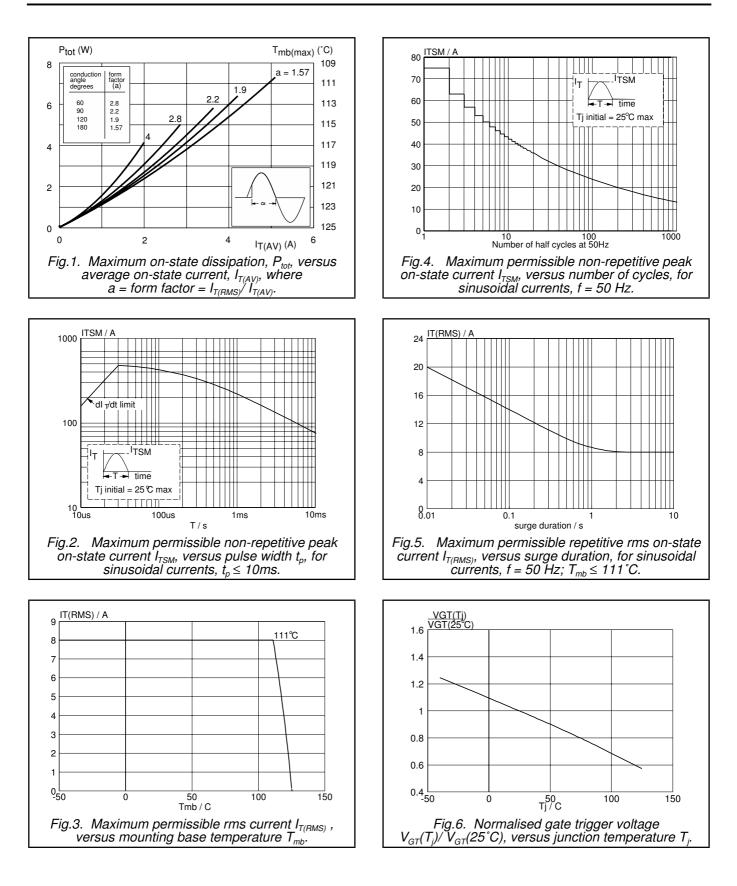
DYNAMIC CHARACTERISTICS

 $T_j = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
dV _D /dt	Critical rate of rise of off-state voltage	$V_{DM} = 67\% V_{DRM(max)}; T_j = 125 °C;$ exponential waveform; $R_{GK} = 100 \Omega$	50	100	-	V/µs
t _{gt}	Gate controlled turn-on time	$I_{TM} = 10 \text{ A}; V_D = V_{DRM(max)}; I_G = 5 \text{ mA};$ $dI_C/dt = 0.2 \text{ A}/\mu\text{s}$	-	2	-	μs
t _q	Circuit commutated turn-off time		-	100	-	μs

BT258 series

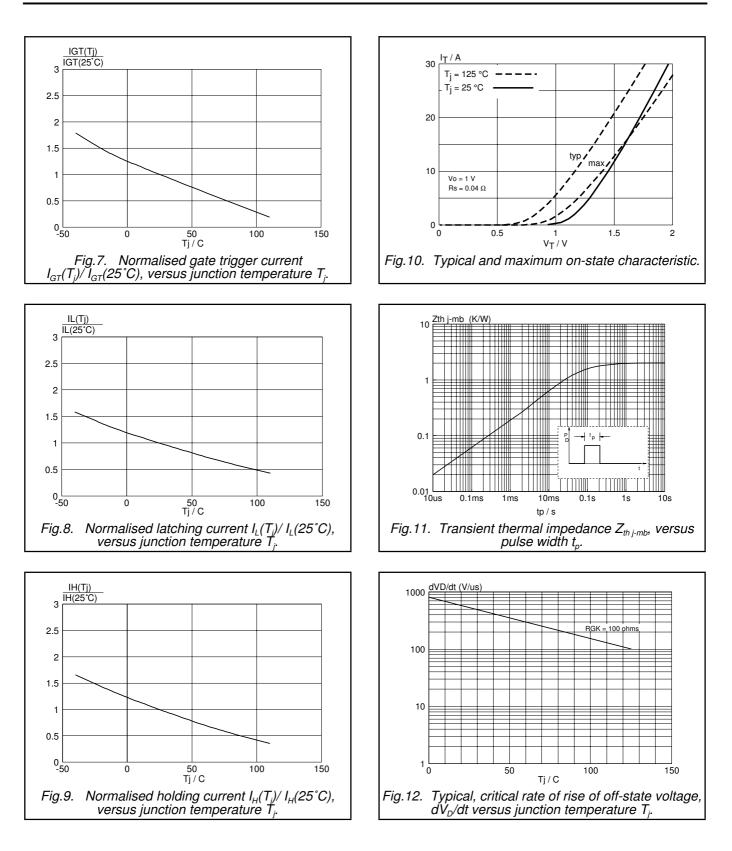
Thyristors logic level



Product specification

BT258 series

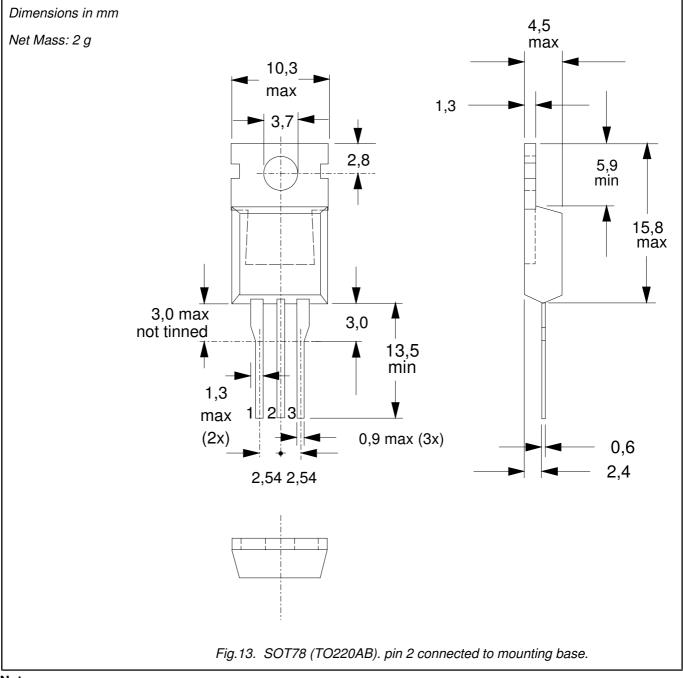
Thyristors logic level



Thyristors logic level

BT258 series

MECHANICAL DATA



Notes 1. Refer to mounting instructions for SOT78 (TO220) envelopes. 2. Epoxy meets UL94 V0 at 1/8".

Legal information

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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Contact information

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